Quantum corrections to the conductivity and Hall coe cient of a two-dimensional electron gas in a dirty A IG aA s/G aA s/A IG aA s quantum well: from the di usive to the ballistic regime

V.T.Renard,^{1,2} I.V.Gomyi,^{3,4} O.A.Tkachenko,^{5,1} V.A.Tkachenko,⁵ Z.D.Kvon,^{5,1} E.B.Okhanetsky,^{5,1} A.I.Toropov,⁵ and J.C.Portal^{1,2,6}

¹GHMFL, MPI-FKF/CNRS, BP-166, F-38042, Grenoble Cedex9, France

² IN SA-Toulouse, 31077, Cedex 4, France

³A.F. Io e Physico-Technical Institute, 194021 St. Petersburg, Russia

⁴Institut fur Nanotechnologie, Forschungszentrum Karlsruhe, 76021 Karlsruhe, Germany

⁵Institute of Sem iconductor Physics, Novosibirsk 630090, Russia

⁶ Institut Universitaire de France, Toulouse, France

(D ated: m ay 19, 2005)

W e report an experim ental study of quantum conductivity corrections in a low m obility, high density two-dim ensional electron gas in a A G aA s/G aA s/A G aA s quantum well in a wide tem perature range (1.5K { 110K). This tem perature range covers both the di usive and the ballistic interaction regim es for our samples. It has been therefore possible to study the crossover between these regim es for both the longitudinal conductivity and the H alle ect. W e perform a param eter free com parison of our experim ental data for the longitudinal conductivity at zero m agnetic eld, the H all coe cient, and the m agnetoresistivity to the recent theories of interaction-induced corrections to the transport coe cients. A quantitative agreem ent between these theories and our experim ental results has been found.

PACS num bers: 73.20 Fz, 73.21.-b, 73.21 Fg

I. IN TRODUCTION

At low temperatures the conductivity of a degenerated two-dimensional electron gas (2DEG) is governed by quantum corrections to the D rude conductivity D. In general, these corrections have two principal origins: the weak localization (W L) and the electron-electron (e-e) interaction¹. Until recently our understanding of the interaction corrections to the conductivity of a 2DEG was based on the seem ingly unrelated theories developed for two opposite regimes: the diusive regime² $k_{\rm B}$ T = h 1. and the ballistic regim $e^3 k_B T = h$ 1. In the di usive regime the quasi-particle interaction time $h=k_{\rm B}T$ is larger than the momentum relaxation time and two interacting electrons experience multiple in purity scattering. In the ballistic regime the e-e interaction is mediated by a single in purity.

Recently, Zala, Narozhny, and Aleiner (ZNA) have developed a new theory of the interaction related corrections to the conductivity^{4,5} that bridges the gap between the two theories known previously^{2,3}. One of the important conclusions of the new theory is that the interaction corrections to the conductivity in both regimes have a common origin: the coherent scattering of electrons by Friedel oscillations. This can be also reform ulated in term s of returns (di usive and ballistic) of an electron to a spatial region which it has already visited. Conform ably to the previous results^{2,3}, the new theory predicts a logarithm ic tem perature dependence of the longitudinal conductivity and the Hall coe cient in the di usive regime, whereas in the ballistic regime the temperature dependence of these param eters becom es linear and T¹ respectively. Finally a further step in the generalization of the interaction theory was realized in Ref. 6 and Ref. 7 who considered application of strong perpendicularm agnetic elds for arbitrary type of disorder potential and in uence of electron-phonon in purity scattering, respectively.

Despite experim ental surge of а activity^{8,9,10,11,13,14,15,16} follow ing the publication of the theory^{4,5}, to our know ledge, no experiment has been reported where the crossover between the two regimes would have been clearly observed. One of the reasons is that the tem perature at which the crossover is expected to occur is given by $k_B T = h$ 0:1 (see Refs. 4,5,6). In the relatively high-mobility 2D systems that are commonly studied the crossover temperature is by far too low to be accessed experimentally (T < 100 mKfor $> 10^{11}$ s). Thus, the ZNA theory has to our know ledge been veried only in the intermediate and ballistic regim es^{17} (k_B T = h = 0:1(10).

To shift the crossover to higher temperatures one should use low mobility samples (sm all). At the same time high carrier densities N_s are necessary in order to maintain high conductivity and avoid strong localization. Note that such samples were already grown and studied^{18,19,20} in the di usive regime, but the crossover between the ballistic and di usive regimes was not considered. In high density 2D systems the characteristic parameter $r_s = E_c = E_F / 1 = N_s^{1=2}$, the ratio between C oulomb energy and Ferm i energy is small ($r_s < 1$) and hence the e ect of e-e interaction is relatively weak. In this case the ZNA theory⁴ predicts insulating like behavior of conductivity d_{xx}=dT > 0 at all temperatures, whereas the \screening" theory³ predicts metallic like behavior d_{xx}=dT < 0 in the high-temperature ballistic

regine. Moreover, for such small r_s the Ferm i liquid interaction constant F_0 , the only parameter in the expressions for the quantum corrections to the conductivity in the theory⁴, can be calculated explicitly.

In this respect low -m obility high-density systems appear to o er certain advantages for testing the theory^{4,5}, as compared to high-mobility low-density systems. Indeed not only they provide an opportunity for studying an experimentally accessible temperature crossover between the di usive and the ballistic interaction regimes but also the comparison between the theory and experin ent requires no thing parameters. Also, in such system s the disorder potential is mostly due to the shortrange in purities which yields alm ost isotropic scattering on im purities as assumed in Refs. 4,5. As shown in Ref. 6, the nature of disorder becom es crucially in portant in the ballistic regime. Finally, the interaction-induced longitudinalmagnetoresistance (MR) _{xx} (B;T) in the ballistic regime has been already studied on systems with longrange¹² and m ixed¹³ disorder, where the theoretical results of R ef. 6 have been con med. However, no experin ental results for $_{\rm xx}$ (B ; T) have been reported so far for low-m obility system s in the ballistic regime.

The aim of the present work is to experim entally study the interaction related corrections to the conductivity, m agnetoresistivity, and the Hall coe cient in a broad tem perature range covering both the di usive and ballistic interaction regimes and the crossover between them. The experimental results obtained in the weak interaction limit are expected to allow for a parameter free com – parison with the ZNA theory for both $_{xx}$ and $_{xy}$. We also compare our results on the MR for short-range disorder with the predictions of R ef. 6.

II. EXPERIMENTAL SETUP

The experimental samples had a 2DEG formed in a narrow (5 nm) A IG aA s/G aA s/A IG aA s quantum well doped in the middle. Such doping results in a low mobility and a high carrier density. A lso in purities located in the layer give rise to a large-angle scattering of electrons. A detailed description of the structure can be found in Ref. 21. Two samples from the same wafer have been studied for which sim ilar results were obtained. Here we present the data obtained for one of the sam ples with the following parameters at T = 1:4K depending on prior illum ination: the electron density N_s = $(2.54 \quad 3.41) \quad 10^{2}$ m^2 and the mobility = (380) 560) am 2 /Vs. The Hallbar shaped samples were studied between 1.4K and 110K in magnetic elds up to 15T using a superconducting magnet and a VTI cryostat and also a ow cryostat (T > 5K) placed in a 20T resistive magnet. The data was acquired via a standard four-term inal lock-in technique with the current 10 nA.

Fig. 1 shows the longitudinal and Hall resistances of the sample as a function of magnetic eld at temperatures up to 110K. As can be seen both are strongly

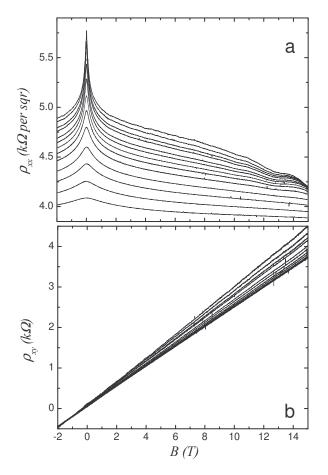


FIG.1: a) Longitudinal resistivity of the sam ple at N_s = $2.56 \quad 10^{12}$ cm² for temperature= 1.4 K, 1.9 K, 3.1 K, 4 K, 7.2 K, 10.25 K, 15.45 K, 21.5 K, 31 K, 46.2 K, 62.8 K, 84.5 K and 110 K from top to bottom . b) H all resistance at the sam e temperatures (from top to bottom).

tem perature dependent. B efore analyzing the role of the quantum corrections in the behavior of the transport coe cients shown in Fig.1, let us estim ate the possible contribution from other unrelated tem perature dependent factors.

First, since the m easurements were performed up to relatively high temperatures, the question of the role of phonon scattering becomes important. In this connection we believe that the following argument can be used. It is well known that in ultra-clean G aAs samples su ciently high values of mobility are reported even at liquid nitrogen temperatures (see, for example R ef. 22,23, where $= 4 - 10^5$ cm²/V s at T = 77K). At these temperature the phonon scattering is the dominant scattering mechanism in these samples and yet the mobilities are still a thousand times larger than in our sample. In our experiment, the pure electron-phonon contribution to the conductivity is thus negligible compared to impurity scattering.

Recently a theory of the interplay between electronphonon and impurity scattering was developed⁷. It was argued that these interference e ects m ight play a signi cant role at interm ediate tem peratures. However, we have evaluated the phonon contribution to be a few percent of the D nude conductivity at 100K. A lso our estim ates show that this contribution is still sm aller than the e-e interaction one. For these reasons the e ect of phonons can be neglected in the entire experim entaltem perature range in these sam ples.

Now, as can be seen in Fig.1, the Hallcoe cient varies with T at low tem peratures but remains practically constant for T > 20K. One might argue that the behavior at low tem peratures could be due to a variation of the electron density with tem perature. However, we believe that this is not the case. Indeed, from the measurements carried out up to 20T where the Shubnikov – de Haas (SdH) oscillations are better resolved, we nd that the density remains constant at T < 30K. Also we nd that the density given by the SdH oscillations is the same as we get from the slope of the Hall resistance at T > 20K where it is T-independent. We conclude therefore that the electron density remains constant in the entire experimental tem perature range and all the data presented in Fig.1 corresponds to N s = 2:56 10^{12} cm 2 .

Having excluded the phonon scattering and the density variation as possible causes of the behavior shown in Fig. 1 we associate the observed temperature dependencies with the quantum corrections to the transport coe cients. Our data will be analyzed in the fram ework of the recent theories^{4,5} valid for a degenerated 2DEG ($k_{\rm B}$ T $E_{\rm F}$). According to Ref. 21 only one subband is occupied in our quantum wells at N $_{\rm s}$ = 2.56 10^{42} cm 2 . A lso $E_{\rm F}$ 1000K and so the theory^{4,5} should apply under our experimental conditions.

III. QUANTUM CORRECTIONS TO THE CONDUCTIVITY TENSOR: BACKGROUND

The longitudinal conductivity is a sum of three components: the D rude conductivity, the W L contribution and the e-e interaction correction. For the correct evaluation of the interaction related correction at B = 0 T, the know ledge of the rst two contributions to the conductivity is essential. Unfortunately, in our case there is no direct means of knowing the value of the D rude conductivity $_{0}^{D}$ because of a considerable (up to 20%) variation of the zero eld conductivity with temperature. On the other hand, to single out the e-e interaction correction, we have to eliminate the weak localization contribution, which m ight be stronger than the interaction correction at B = 0.

The W L correction to the conductivity at low tem peratures and m agnetic elds is described by a well-known expression²⁴ involving digam m a functions. However, at high enough tem peratures and/or m agnetic elds (when the contribution of non-di usive paths becom esm ore and m ore pronounced) the W L correction is given by a rather com plicated analytical expression²⁵. N evertheless, there exists a m ethod (see the next Section) that can be used for the evaluation of all the three contributions to the conductivity at zero magnetic eld basing on the know \bot edge of the high-B behavior of the magnetoconductivity. This m ethod has the advantage that one can forgo the usualprocedure of thing the low eld data with the theoretical expressions for the W L magnetoresistance^{24,25}, thus elim inating a possible source of error at this stage.

A general form ula for the conductivity tensor in a m agnetic eld can be derived using the quantum kinetic equation of R ef. 4. The longitudinal and the H all conductivities can be written for $k_B T = E_F$ in the following form ²⁶

$$x_{X} (T;B) = \frac{D(T)}{1 + \frac{2}{c}^{2}(T)} + \frac{D_{ee}}{ee} (T) + \frac{W_{x}}{xx} (T;B);$$
(1)
$$x_{Y} (T;B) = \frac{\frac{1}{c} (T) D(T)}{1 + \frac{1}{c} (T)} + \frac{1}{c} (T) - \frac{H}{co} (T)$$

$$x_{Y}(T;B) = \frac{1}{1 + \frac{2}{c}} \frac{(T)}{2} \frac{(T)}{1} + \frac{1}{c} (T) = \frac{H}{ee}(T) + \frac{W}{x_{Y}} (T;B);$$
(2)

G enerally, the zero-B D rude conductivity $_{\rm D}$ (T) depends on T due to the interaction-induced renormalization of both the transport scattering time (T) and the Ferm ivelocity $v_{\rm F}$ (T). Strictly speaking, the cyclotron frequency $!_{\rm c}$ also depends on T via the renormalization of the effective mass m (T); how ever, it appears in (1) and (2) only in combination $!_{\rm c}$ (T) so that one can absorb its renormalization into the T-dependence of the elective scattering time. W hile the rst terms in (1) and (2) have the structure of the classical D rude conductivity in a -nite B, the terms $\sum_{\rm ee}^{\rm D-i}$ (T) and $!_{\rm c}$ (T) $\sum_{\rm ee}^{\rm H}$ (T) appear as quantum corrections to the D rude term s.

The expressions (1) and (2) are justified under the condition dition

$$!_{c} = + 2^{2} k_{B} T = h$$
 (3)

which allows one to neglect SdH oscillations in the present case of short-range in purity potential. The sam e condition governs the strength of the in uence of magnetic eld on the collision integral in the kinetic equation⁴ and allows one to neglect cyclotron returns to the same im purity. Under this condition, the bending of relevant electron trajectories by the magnetic eld is weak. It is taken into account by a proper de nition of the the B-independent quantities $_{D}$ (T); (T); Di (T); $_{ee}^{H}$ (T): This makes it possible²⁶ to extract the and interaction-induced corrections to the conductivity at B = 0 from the magnetoconductivity obtained in relatively strong magnetic elds, see Section IV. The condition (3) is fulled in the whole range of relevant T and B we address in this work.

The term $\sum_{e=}^{D i}$ in Eq. (1) corresponds to the \di usive" contribution of e-e interactions, which is due to the coherent processes involving multiple in purity scattering

^{D i} diverges logarithevents. In the di usive regime, \tilde{T} (\tilde{T}) / ln ($k_{\rm B} T = h$) [we m ically² with decreasing T , note in passing that, in contrast to Eqs. (9) and (10) below, this logarithm ic contribution is cut o by h= rather than by E_F]. At high tem peratures the contribution of di usive paths is expected to vanish, since the probability of \di usive" returns involving m ore than one impurity-scattering is suppressed in the ballistic regime (each additional impurity scattering yields an extra fac- $_{ee}^{D i}$ in (1) also takes $tor h=k_B T$). In e ect, the term into account the in uence of the magnetic eld on the return probability determ ining the correction to the Tdependent part of the e ective transport time, see discus- $\frac{D i}{2}$ dom inates in sion in Ref. 6. This contribution to $\frac{1}{ee}$ in Eq. (2), the the ballistic regime. As for the term contribution of di usive paths to it is exactly zero², so that this term is completely determined by the in uence of the magnetic eld on the collision integral. Therefore, ^H_{ee} has no logarithm ic diverin the diusive regime Di ee• $qency^2$, unlike

Taking into account the e-e interaction e ects related to the scattering on a single in purity results in the T-dependent renormalization^{3,4,26} of (T). The T-dependence of $_{\rm D}$ (T) in the ballistic limit is dom inated by the T-dependence of (T) since the interactioninduced correction to the Fermi velocity yields a weaker T-dependence. Thus, in the ballistic limit the linear-in-T interaction correction to the zero-B conductivity⁴ enters Eq. (1) only via the renormalized transport scattering time (T) in the rst term (both in the numerator and the denominator).

The terms \bigvee_{xx}^{WL} and \bigvee_{xy}^{WL} in Eqs. (1) and (2) are the WL corrections to the longitudinal and H all conductivities, respectively. A ctually, the WL corrections arise solely from the renorm alization of the transport scattering tim e^{27} and hence they can be completely absorbed into the rst \classical" terms in (1) and (2) via the B dependent correction to (T).

A generalm ethod for the analysis of the m agnetotransport data is based on Eqs. (1) and (2). For a given temperature one can treat the B -independent quantities $_{D}$ (T); (T); $_{ee}^{Di}$ (T); and $_{ee}^{H}$ (T) as four tting parameters to the two experimental curves: $_{xx}$ (T;B) vs B and $_{xy}$ (T;B) vs B. Under the assumption that the W L corrections are suppressed it follows from Eqs. (1) and (2) that

$$_{xx}$$
 (T;B) = $\frac{_{xy}$ (T;B)}{!_{c}} + $\stackrel{\text{Di}}{\text{ee}}$ (T) $\stackrel{\text{H}}{\text{ee}}$ (T):

This equation allows one to nd the values of (T) from the slope of $_{xx}$ (T;B) vs $_{xy}$ (T;B)=! c dependence. Then $_{D}$ (T) and $_{ee}^{D i}$ (T) can be found from the $_{xx}$ (T;B) vs $[1 + !_{c}^{2} {}^{2}$ (T)]¹ plot. A detailed analysis of the magnetoconductivity based on this procedure will be published elsewhere²⁸. In this paper we will concentrate on the zero-B interaction-induced correction to $_{xx}$: For this purpose a simpler thing procedure described in Section IV is su cient.

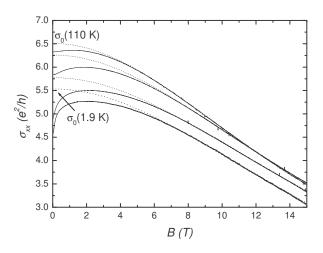


FIG. 2: Experim ental longitudinal conductivity at T = 1.9K, 10.25K, 62.8K and 110K from bottom to top (solid line) and the t to Eq. (1) according to the description in the text. The result is then extrapolated to B = 0T (dotted line) for the same tem peratures.

IV . LONG IT U D IN A L CONDUCT IV IT Y AT B = 0: EXPER IM ENTAL M ETHOD

Let us describe how the experim ental quantum corrections were extracted from the row data and then turn to the analysis of the obtained corrections. The main idea of our method is to use the M R and H all data obtained in a relatively strong magnetic eld, where the weak localization is suppressed, to nd the value of interaction-induced corrections in the lim it of zero magnetic eld.

W ith the magnetic eld increasing, the M R in Fig.1a goes through two distinct types of behavior. An abrupt drop of resistance at low elds and then a much weaker magnetic eld dependence at higher B. As is wellknown the weak localization is suppressed at magnetic elds larger than $B_{tr} = h = (2el^2)$, where 1 is the mean free path. In our samples B_{tr} 1.5T that roughly coincides with the eld at which the crossover from the one type of M R to the other takes place. We conclude therefore that the strong M R observed at low elds can be associated with the W L suppression in our samples and that the M R observed at higher elds must be attributed entirely to the e-e interaction e ects².

As a rst step of our procedure, the experimental values of the longitudinal and Hall conductivities are obtained by inverting the resistivity tensor using the data shown in Fig. 1. The result for the longitudinal conductivity is shown in Fig. 2. The weak localization correction dominates at low elds but is suppressed at $B > B_{\rm tr}$. Therefore, at $B = B_{\rm tr}$ the shape of the term in Eq. (1). The term $\int_{ee}^{D-1} i$, which is B-independent, should only result in a vertical shift of this contribution. At low term perstures we experimentally is the MC corresponding

to di erent tem peratures form s parallel vertically shifted traces (see Fig. 2) whose shape is given by the rst term in Eq. (1) with a T-independent . At tem peratures larger than 30K the shape of the curves begins to deviate slightly from that of the low tem perature traces. This change is attributed to the renorm alization of the scattering time by e-e interactions in the ballistic lim it⁴.

To interpolate between all the relevant regimes (diusive vs ballistic, classically weak B vs strong B) we use a simplied version of Eq. (1). W ithin this procedure, we attribute the T-dependence of $_{\rm D}$ (T) solely to the T-dependence of (T), using

$$_{\rm D}$$
 (T) = e^2 n (T)=m : (4)

This am ounts to treating all the interaction-induced corrections to the collision integral related to $_{\rm D}$ (T) as the renorm alization of the elective transport scattering time. Further, we assume that the T-dependence of the product ! $_{\rm C}$ in the classical term s in (1) and (2) is the same as the T-dependence of $_{\rm D}$ (T). This approximation [used earlier together with Eq. (5) in Refs. 20,29] yields the proper asymptotics of the conductivity correction, that are governed by $_{\rm Dei}^{\rm Dei}$ and (T) in the di usive and the ballistic regimes, respectively.

It is possible to determ ine the scattering time by tting the curves for B > 6T using Eq. (1) at a given value of T with (T) and ${}_{ee}^{D\,i}$ (T) as thing parameters (see Fig. 2). This was done for all the temperatures and the results for both ${}_{ee}^{D\,i}$ and (T) are presented in Fig. 3. The momentum relaxation time is observed to increase linearly with temperature at T > 20K. This linear behavior is expected in the ballistic lim $\pm^{3,4}$. As for the term ${}_{ee}^{D\,i}$, it is observed to decrease in am plitude with temperature increasing and to vanish at T > 20K. It is important to stress that a signi cant change in the behavior of these two parameters occurs at T = 20K.

Once the for B > 6T , the term

$$\sim_{\rm xx} (T;B) = \frac{e^2 n}{m} \frac{(T)}{1 + !_c^2 (T)} + e^{Di} (T)$$
(5)

was then extrapolated for each of the curves down to B = 0 (see Fig.2). We believe that the value

$$_{D}(T) = \sim_{xx} (T; B = 0) = _{D}(T) + _{ee}^{Di}(T)$$
 (6)

obtained at B = 0 is free of the T-dependent W L contribution³⁰.

Finally, the temperature independent term ${}^{D}_{0}$ was subtracted from ${}_{0}$ at all temperatures. This was made to obtain the value of the e-e interaction correction to the conductivity

$${}^{\text{ee}}_{\text{xx}} (T; B = 0) = {}_{0} (T) {}^{\text{D}}_{0}$$
(7)

which is presented in gure 4. The value $D_0^0 = (6:3 \ 0:1)$ $e^2 = h$ was found from the analysis of the M R data as the value of the conductivity at the point $!_c = 1$; where the M R curves corresponding to the di usive range of T intersect, see Section V II and Eq. (19) there.

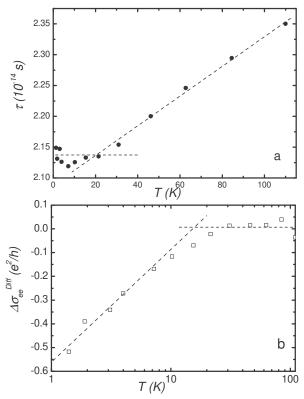


FIG.3: Obtained values of the scattering time (a) and of the term $\stackrel{D \ i}{ee}$ (b). A clear change in their behavior is observed from constant (logarithm ic) to linear (constant) at T 20K. The lines are a guide for the eyes.

V. LONG IT UD IN AL CONDUCT IV IT Y AT B = 0: EXPER IM ENT VS THEORY

A coording to R ef. 4, the e-e interaction correction to the conductivity is given by the following expressions:

$$_{\rm xx}^{\rm ee} = _{\rm C} + 3 _{\rm T};$$
 (8)

where

$$c = \frac{e^{2}}{h} \frac{k_{B} T}{h} = 1 = \frac{3}{8} f (k_{B} T = h)$$
$$\frac{e^{2}}{2^{2} h} \ln \frac{E_{F}}{k_{B} T}$$
(9)

is the charge channel correction and

$$T = \frac{F_0}{[l + F_0]} \frac{e^2}{h} \frac{k_B T}{h} = 1 = \frac{3}{8} t (k_B T = h; F_0)$$

$$1 = \frac{\ln (l + F_0)}{F_0} = \frac{e^2}{2 k_B^2} \ln \frac{E_F}{k_B T}$$
(10)

is the correction in the triplet channel. The detailed expression of f(x) and $t(x;F_0)$ can be found in Ref. 4.

In these expressions the linear-in-T term is due to the renorm alization of (T) by Friedel oscillation. This contribution comes from $_{\rm D}$ (T) in Eq. (6) and dom inates in

the ballistic lim it $k_B T = h$ 1. In the di usive lim it, the conductivity correction is determ ined by the logarithm ic term s, which can be roughly split in two parts as follows: ln ($E_F = k_B T$) = ln ($h = k_B T$) + ln ($E_F = h$): Here the rst (singular) term comes from D_{ee}^{i} in Eqs. (1) and (6). The second (constant) term is the contribution of D_{D} (T). In the ballistic regime D_{ee}^{i} gets suppressed, so that the whole logarithm ic term ln ($E_F = k_B T$) comes from D_{D} (T).

It is worth m entioning that for sm all r_s the interaction constant F_0 as function of r_s can be calculated explicitly. As suggested by ZNA⁴ we used:

$$F_0 ! \frac{1}{2} \frac{r_s}{r_s + \frac{p}{2}} = 0.1$$
 (11)

in the rst line of $_{\rm T}$ (this form related to Friedel oscillations) and

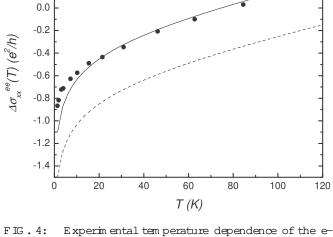
$$F_{0} ! \frac{1}{2} \frac{r_{s}}{p \frac{r_{s}}{2} r_{s}^{2}} \ln \frac{p \frac{1}{2} + p \frac{1}{2} r_{s}^{2}}{p \frac{1}{2} p \frac{1}{2} r_{s}^{2}} = 0.17$$
(12)

in the second line so that no additional tting parameter has been introduced. The calculations were done for $r_s = 0.35$ corresponding to the electron density in our sam ple.

In Fig. 4 we plot the theoretical curve (dashed line) calculated for our system parameters using Eqs. (8), (9), and (10), as well as the experimental data points. As can be seen, there is a system atic shift of the experimental points with respect to the theoretical curve. This shift can be explained by the fact that ZNA theory describes only the temperature dependence of the conductivity but not the magnitude of the total interaction-induced contribution.

Firstly, in addition to the correction ee given by Eqs. (8), (9), and (10), there is a large T-independent interaction-induced contribution to conductivity which is due to the T-independent part of the renorm alization (screening) of impurities by Friedel oscillations [see Eq. (3.33) of Ref. 4]. For $r_s > 1$; this contribution is of the same order in magnitude as the value of the D rude conductivity of a noninteracting electron gas, while for 1 it contains an additional factor rg.However,in r. the presence of interactions this contribution cannot be experimentally separated from the noninteracting part of the D rude conductivity. Therefore, the value of $\begin{bmatrix} D \\ 0 \end{bmatrix}$ used in Eq. (7) already takes into account this screeninginduced term , so that the observed shift cannot be explained in this way.

Secondly, the logarithm ic term s in (9) and (10) yield a T-independent contribution which depends on the ultraviolet cuto . It is worth noting that E_F appears in Eqs. (9) and (10) only due to the contribution of $_D$ (T) (this fact becomes important in a nite magnetic eld). It follows that, similarly to the linear-in- E_F term discussed above, the T-independent term $\ln (E_F = h)$ is also already absorbed in $_0^D$ when the latter is found from the analysis of the MR data. Thus it is not surprising to observe a vertical shift between the predictions



0.2

FIG. 4: Experim ental tem perature dependence of the ee correction to conductivity (black dots). The dashed line corresponds to the rst evaluation of the model of Ref. 4. The solid line corresponds to the theory taking into account the tem perature independent contribution (see the text).

of Ref. 4 written in the form of Eqs. (9) and (10) with $\ln (E_F = k_B T)$ and the experimental data obtained using a speci c choice of the value of the D rude conductivity.

In Fig. 4 we shifted the theoretical curve given by Eqs. (9) and (10) upward by replacing E_F by a quantity of order of h= in the logarithm ic term s (solid line).

A reasonably good quantitative agreem ent between the model of Ref. 4 and the data is found for the entire temperature range. Note that contrary to the previous works^{8,9,10,11,13,14} we have used no tting parameter. Moreover we nd that using the interaction constant F₀ as a tting parameter does not result in a better agreement between theory and experiment.

Let us now return to the analysis of Fig. 3 which we believe to reveal in portant inform ation. Indeed, the to-Di (T) tal correction to the conductivity is the sum of and a ballistic contribution which is proportional to (T). As can be seen the logarithm ic di usive part vanishes at T > 20K when the ballistic part starts to vary linearly with tem perature. Therefore we believe that Fig. 3 establishes a crossover from the di usive to the ballistic lim it in the behavior of the interaction-induced correction to the zero-B conductivity. This change of behavior is observed at T 20K. This is in a qualitative agreement with the ZNA theory, predicting the crossover to occurat $k_B T = h$ 0:1 which corresponds in our case to Т 30K.

Finally, not only Fig. 3 shows that the scattering time e ectively varies linearly with temperature at high temperature^{3,4} but it also shows that the sign of the variation is positive (i.e. insulating like). It is due to the fact that at small r_s the exchange (singlet) contribution is more important than Hartree (triplet) contribution⁴. W hile predicted by ZNA theory at low interaction this behavior is not allowed by the screening theory³ which does not take into account the exchange part in the cal-

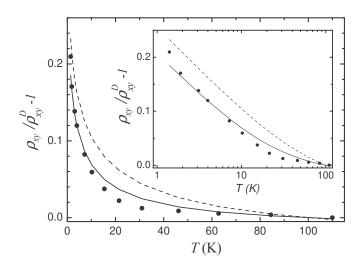


FIG. 5: Temperature dependence of the Hall coe cient (dots) compared to Eq. (13) (dash line) and to Eq. (13) with = 0.065 (solid line). The same data are plotted in a logarithm ic scale.

culation of the corrections.

VI. HALL EFFECT

W e now turn to the analysis of the H all data presented in Figure.1b. A coording to R ef.5 the H all resistivity m ay be w ritten as:

$$xy = {}^{D}_{H} + {}^{C}_{xy} + {}^{T}_{xy}$$
(13)

where $_{H}^{D}$ is the classical H all resistivity and $_{xy}^{C}$; $_{xy}^{T}$ are the corrections in the charge and triplet channel. These corrections are given as follows:

$$\frac{{}_{Xy}^{C}}{{}_{H}^{D}} = \frac{1}{{}_{E}{}_{F}} \ln 1 + \frac{h}{{}_{k_{B}}{}_{T}}$$
(14)

$$\frac{{}_{XY}^{T}}{{}_{H}^{D}} = \frac{3h (k_{B} T = h; F_{0})}{E_{F}} \ln 1 + \frac{h}{k_{B} T}$$
(15)

The detailed expression for $h(x;F_0)$ can be found in Ref. 5, $=\frac{11}{192}$ and the value of $_{\rm H}^{\rm D}$ is obtained from the high temperature curves for which $_{\rm xy}$! 0. Therefore according to the theory of the e-e interaction⁵ one should observe a logarithm ic temperature dependence of $_{\rm xy} = _{\rm H}^{\rm D}$ 1 in the di usive regime replaced by a hyperbolic decrease 1=T at higher temperatures.

Figure 5 shows how this prediction works in our case. A simple calculation (carried out without any attempt at thing the experiment) results in the dashed curve ($F_0 = 0.17$). This prediction is compared with the experimental correction (black dots). At each temperatures the H all coe cient was obtained by linearly thing the experimental curves shown in Fig. 1b. The corresponding range of magnetic eld satis es ! c < 0.6 0.8; which

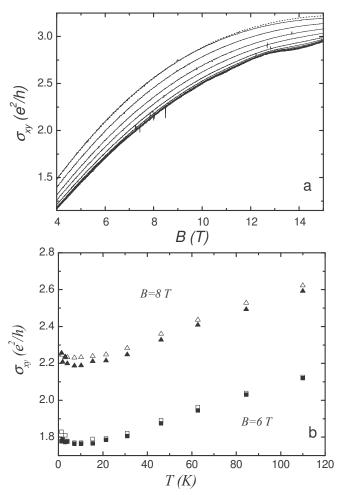


FIG.6: a) Transverse conductivity as function of magnetic eld (shown in the range of B relevant to the interactioninduced corrections) for the tem peratures listed in the caption of Fig. 1. The dotted line corresponds to Eq. (16) taken at T = 110K; b) Transverse conductivity as function of T for two di erent values of magnetic elds (black symbols). It is compared to the value calculated using Eq. (16) (Open symbols).

allowed us to neglect the nite-B corrections to Eqs. (13)-(15) in our analysis. As shown in Ref. 6, such corrections are small even at ! $_{\rm c}$ 1 because of small num erical factors, so that one can safely use the results of Ref. 5 obtained in the limit B ! 0 in a rather wide range of B.

On the whole, there is a qualitative agreem ent between theory and experiment but the quantitative agreement is lacking. Using F_0 as a tting parameter does not improve the agreement. Nevertheless we have found, that if the coecient = $\frac{11}{192}$ ' 0:18 is replaced by = $\frac{4}{192}$ ' 0:065, then the theoretical curve (the solid line) ts the experimental dependence quite well.

This result m ight be related to an anisotropy of electron scattering in the sample which reduces the electron return probability and so weakens the correction at low elds (! $_{\rm c}$ 1). The reduction of the pre-factor could just be the way in which this anisotropy reveals itself

since the correction is proportional to in the ballistic regime tic limit. It is worth noting, that in the ballistic regime the correction to the H all coe cient is more sensitive to the anisotropy of in purity scattering than the leading correction to the longitudinal conductivity. This is because the relevant processes giving rise to $_{xy}$ involve at least three in purity scattering events, while those leading to the linear-in-T correction to $_{xx}$ involve a single backscattering. C learly, each large-angle scattering event yields a reduction factor even for the weak anisotropy of scattering.

Finally, in Fig. 6 we show the experimental data points for the transverse conductivity tensor as a function of magnetic eld (Fig. 6a) and as function of temperature for two di erent values of magnetic eld (Fig. 6b). The conductivity is observed to be temperature independent at low temperatures and vary linearly with temperature at high temperatures. While conform to the theoretical prediction in the di usive regime ($\frac{H}{ee} = 0$ and

 $_{xy}^{W L} = 0$, according to Ref. 2), the behavior at high tem peratures is less obvious. However, this behavior follows from Eq. (2) which takes into account the ballistic renorm alization of the scattering time. The measured values of the H all conductivity are indeed well com pared to values of $_{xy}$ (T) calculated using the sim pleD rude-like form ula:

$$_{xy} = \frac{e^{2}n}{m} \frac{!_{c}^{2} (T)}{1 + !_{c}^{2} (T)};$$
(16)

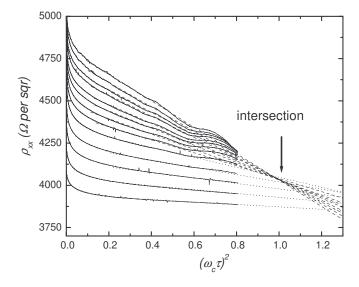
In this formula we neglected term $s!_c$ (T) $\stackrel{H}{=}$ (T) and

 $_{xy}^{W L}$ (T;B) from Eq. (2) and used Eq. (4) for $_{D}$ (T). To evaluate $_{xy}$ we used the values of the scattering time shown in Fig. 3. Again the data are well described by the model which includes notting parameter. Note that we also calculated the expected eld dependence at T = 110K [see dotted curve in (Fig. 6a)] which also reproduced well the experimental data. A more detailed analysis of the H all conductivity within the general method outlined in Sec. III [taking into account all the terms in Eq. (2)] will be presented elsew here²⁸.

V II. LONGITUD INAL MAGNETORESISTANCE

Let us return to the analysis of the longitudinal resistivity $_{xx}$ (B) shown in Fig.1. This analysis is aimed to obtain a consistent description including all the transport coe cients, $_{xx}$ (B), $_{xx}$ (B), $_{xy}$ (B), and $_{xy}$ (B). Furtherm ore, the behavior of $_{xx}$ (B) in the ballistic regime is determ ined by more subtle e ects as compared to the behavior of the conductivity tensor. It turns out that in the longitudinal M R, unlike in the conductivity com – ponents, the leading B-independent e-e correction to cancels out. In fact, the T dependence of $_{xx}$ (B) re ects the weak in uence of magnetic eld on the collision integral in the quantum kinetic equation of R ef. 4.

As discussed in Sec. IV, the low -B part of the curves is dom inated by the W L-induced M R, while the M R for



8

FIG.7: xx plotted as a function of $(!_c)^2$ for the tem peratures listed in the caption of Fig.1. The dashed lines are the extrapolation of the linear behavior of the curves corresponding to the di usive regime. They cross each other at $!_c = 1$. The dotted lines represent the extrapolation of the curves in the ballistic regime.

 $B > B_{tr}$ is governed by the interaction e ect. In the di usive regime $k_B T = h$ 1, the interaction {induced resistivity correction,

$$\frac{xx (B)}{D} = \frac{1}{2 E_{F}} (!_{c})^{2} + 3 1 \frac{\ln (1 + F_{0})}{F_{0}}$$

$$\ln \frac{h}{k_{B} T}$$
(17)

(^D is the classical D rude resistivity), gives rise to a parabolic M R $_{xx} = _{xx}(B) _{xx}(B = 0)$ in arbitrary magnetic $eld^{31,32}$.

In the ballistic regime, as shown in Ref. 6, the interaction {induced M R remains quadratic in magnetic eld, while the T behavior of the proportionality ∞e^{-1} cient depends on the type of disorder. In the present case of short-ranged in purities, Ref. 6 predicts the following ballistic (k_B T = h 1) asymptotic behavior of the M R for h! $_{\rm C}$ 2 2k_B T:

$$\frac{xx}{D} = (!_{c})^{2} \frac{1+3g(F_{0})}{2 E_{F}} \frac{17 h}{192k_{B} T}; \quad (18)$$

where the function $g(F_0)$ describes the contribution of the triplet channel. It is worth stressing that in highdensity systems with r_s 1 (i.e. for $F_0 j$ 1), the parabolic M R is dominated by the contribution of the singlet channel and hence is negative.

Equations (17) and (18) can be obtained by inverting the conductivity tensor given by Eqs. (5) and (16). One can see that the classical part of the conductivity tensor [i.e. Eq. (16) and the rst term in Eqs. (1) and (5)] does not yield B dependence of the resistivity, even when

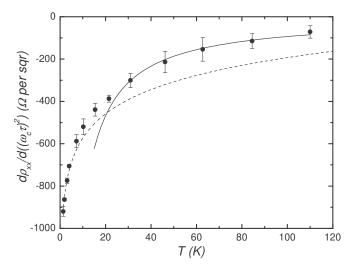


FIG.8: Slope of the curves shown in Fig.7 compared to the theoretical predictions. The dashed line corresponds to the di usive regime (Eq. (17)) and the solid line to the ballistic limit (Eq. (18)).

the interaction e ects are taken into account through the T dependence of (T). Indeed, neglecting the term

 $\stackrel{D\,i}{\underset{ee}{}^{e}}$ (T) one gets $_{xx}$ (T) = m =e²n (T) which is independent of B. Thus the MR is solely generated by the term $\stackrel{D\,i}{\underset{ee}{}^{e}}$. We remind the reader that in the ballistic regime $\stackrel{D\,i}{\underset{ee}{}^{e}}$ appears to be dom inated by the e ect of magnetic eld on the collision integral, see Sec. III. Thus, we conclude that the main source of the MR for T > 20 30K is the weak B dependence of the transport scattering time.

Let us now compare our experim ental data with the above theoretical predictions. It is worth mentioning that the com parison is again param eter free. Figure 7 presents the longitudinal resistivity as a function of $(!_{c})^{2}$. It shows that the MR is indeed parabolic and negative. The slope of the curves $_{\rm xx}$ vs (! $_{\rm c}$)² was obtained in the relevant ranges $(!_{c})^{2} = 0:1$ 0:4 for the curves corresponding to T < 20K and for $(!_{c})^{2} > 0.2$ for T > 20K. This has allowed us to reduce the in uence of W L in the high T data and the SdH oscillations in the low T data. The slope of these lines is presented in gure 8. The error in the determ ination of the slope due to the choice of the evaluation range was estimated from the deviations obtained using the interval 0:2 0:35 of $(!_c)^2$ for the linear t. In Fig. 7 we have extrapolated the M R lines to the region of higher magnetic elds $!_{c}$ 1. From this plot we again clearly see the crossover between the di usive and the ballistic regimes which occurs at T 20K. Indeed the lines for T < 20K intersect each other at a single point close to $(!_{c})^{2} = 1$, as predicted by the diusive expression (17). As follows from Eq. (17), at

the intersection point the quantum correction to the longitudinal resistivity is zero, so that the value of $_{xx}$ at this point corresponds to the classicalD rude value of the resistivity:

$$_{\rm xx} (!_{\rm c} = 1) = {}^{\rm D} = 1 = {}^{\rm D}_{0} :$$
 (19)

This value of D_0^D was used in Sec. IV to nd the magnitude of the interaction-induced conductivity correction at B = 0. For higher temperatures (T > 20K), the M R lines in Fig. 7 no longer intersect each other at a single point. At this point the system enters the crossover region, where the T-dependence of D_0 (T) starts to become important.

The proportionality coe cient of $_{xx}$ vs $(!_{c})^{2}$ dependence is compared in Fig.8 to the theoretical asymptotics given by Eqs. (17) and (18). In (17) we used the \di usive" value $F_{0} = 0.17$ given by Eq. (12). In Eq. (18) we used $g(F_{0}) = F_{0} = (1 + F_{0})$ with $F_{0} = 0.1$ given by Eq. (11). This is consistent with the above observation that the \ballistic" M R is mostly due to the B - dependent corrections to the collision integral. An alm ost perfect quantitative agreem ent between the predictions of R efs. 31, 32 and 6 and the experimental data is found for both di usive and ballistic tem perature regimes.

VIII. CONCLUSION

In conclusion, we have presented a study aim ing at observing the crossover from the di usive to the ballistic regime in the weak interaction limit. We nd strong evidences of such crossover in the obtained measurements. We realized a parameter free comparison of our experimental data for the longitudinal conductivity and H all coe cient to the recent ZNA theory as well as the longitudinal resistivity to the theory of Ref. 6. We nd these theories to be in a good qualitative agreement with our experimental results.

A cknow ledgm ents

W e are very grateful to A.Dm itriev, A.G erm anenko, G.M inkov, A.M irlin, and B.N arozhny for useful discussions. This work was supported by PICS-RFBR (Grant No 1577.), RFBR (Grants No 02-02-16516, 05-02-17800, and 05-02-17802), NATO, INTAS (Grant No 01-0014), DFG-Schwerpunktprogram m \Quanten-Hall-System e", program s \P hysics and Technology of N anostructures" of the Russian m inistry of Industry and Science, \Low dimensional quantum structures" of RAS, and \Russian Scienti c School" (Grant No 2192 2003 2).

E lectronic address: renard@ grenoble.cnrs.fr

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